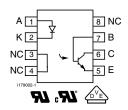
VO205AT, VO206AT, VO207AT, VO208AT

Vishay Semiconductors

Optocoupler, Phototransistor Output, with Base Connection in SOIC-8 Package





FEATURES

- High BV_{CEO}, 70 V
- Isolation test voltage, 4000 V_{RMS}
- Material categorization: for definitions of compliance please see www.vishav.com/doc?99912





COMPLIANT

AGENCY APPROVALS

- <u>UL</u>
- cUL
- DIN EN 60747-5-5 (VDE 0884-5), available with option 1

DESCRIPTION

The VO205AT, VO206AT, VO207AT, VO208AT are optically coupled pairs with a GaAs infrared LED and a silicon NPN phototransistor. Signal information, including a DC level, can be transmitted by the device while maintaining a high degree of electrical isolation between input and output. This family comes in a standard SOIC-8A small outline package for surface mounting which makes them ideally suited for high density application with limited space.

ORDERING INFORMATIO	N						
v o	2 0	# A	Т	SOIC-8			
	PART NUMBER			6.1 mm			
AGENCY CERTIFIED / PACKAGE		CTF	R (%)				
UL, cUL	40 to 80	63 to 125	100 to 200	160 to 320			
SOIC-8	VO205AT	VO206AT	VO207AT	VO208AT			
ABSOLUTE MAXIMUM RATINGS (T _{amb} = 25 °C, unless otherwise specified)							

ABSOLUTE MAXIMUM RATINGS (T _{amb} = 25 °C, unless otherwise specified)							
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT			
INPUT	<u> </u>						
Peak reverse voltage		V_{R}	6	V			
Forward continuous current		I _F	60	mA			
Peak forward current	1 μs, 300 pps	I _{FM}	1	A			
Power dissipation		P _{diss}	90	mW			
Derate linearly from 25 °C			1.2	mW/°C			
OUTPUT							
Collector emitter breakdown voltage		BV _{CEO}	70	V			
Emitter collector breakdown voltage		BV _{ECO}	7	V			
Collector-base breakdown voltage		BV _{CBO}	70	V			
I _{Cmax. DC}		I _{Cmax. DC}	50	mA			
I _{Cmax} .	t < 1 ms	I _{Cmax.}	100	mA			
Power dissipation		P _{diss}	150	mW			
Derate linearly from 25 °C			2	mW/°C			
COUPLER	<u>.</u>						
Isolation test voltage		V _{ISO}	4000	V _{RMS}			
Total package dissipation (LED and detector)		P _{tot}	240	mW			
Derate linearly from 25 °C			3.3	mW/°C			
Operating temperature		T _{amb}	-40 to +100	°C			
Storage temperature		T _{stg}	-40 to +150	°C			
Soldering time	at 260 °C	T _{sld}	10	S			

Note

Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. Functional operation of the device is not
implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute
maximum ratings for extended periods of the time can adversely affect reliability.



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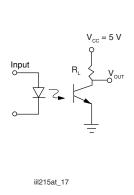
ELECTRICAL CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified)								
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT		
INPUT								
Forward voltage	$I_F = 10 \text{ mA}$	V_{F}	-	1.3	1.5	V		
Reverse current	V _R = 6 V	I _R	1	0.1	100	μΑ		
Capacitance	$V_R = 0 V$	C _O	ı	13	-	pF		
OUTPUT								
Collector emitter breakdown voltage	I _C = 100 μA	BV _{CEO}	70	-	-	V		
Emitter collector breakdown voltage	I _E = 10 μA	BV _{ECO}	7	10	-	V		
Collector base breakdown voltage	$I_{C} = 100 \mu A$	BV _{CBO}	100	-	-	V		
Collector base current		I _{CBO}	-	-	1	nA		
Emitter base current		I _{EBO}	1	-	1	nA		
Collector emitter leakage current	V _{CE} = 10 V	I _{CEO}	-	5	50	nA		
Saturation voltage, collector emitter	$I_C = 2 \text{ mA}, I_F = 10 \text{ mA}$	V _{CEsat}	-	-	0.4	V		
COUPLER								
Capacitance, input to output		C _{IO}	ı	0.5	-	pF		

Note

• Minimum and maximum values were tested requierements. Typical values are characteristics of the device and are the result of engineering evaluations. Typical values are for information only and are not part of the testing requirements.

CURRENT TRANSFER RATIO							
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
		VO205AT	CTR	40	-	80	%
	1 10 m A V 5 V	VO206AT	CTR	63	-	125	%
I _C /I _F	$I_F = 10 \text{ mA}, V_{CE} = 5 \text{ V}$	VO207AT	CTR	100	=	80	%
		VO208AT	CTR	160	-	320	%

SWITCHING CHARACTERISTICS								
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT		
Turn-on time	$I_{C} = 2 \text{ mA}, R_{L} = 100 \Omega, V_{CC} = 10 \text{ V}$	t _{on}	-	3	-	μs		
Turn-off time	$I_C = 2 \text{ mA}, R_L = 100 \Omega, V_{CC} = 10 \text{ V}$	t _{off}	-	3	-	μs		
Rise time	$I_{C} = 2 \text{ mA}, R_{L} = 100 \Omega, V_{CC} = 10 \text{ V}$	t _r	-	3	-	μs		
Fall time	$I_{C} = 2 \text{ mA}, R_{L} = 100 \Omega, V_{CC} = 10 \text{ V}$	t _f	-	2	-	μs		



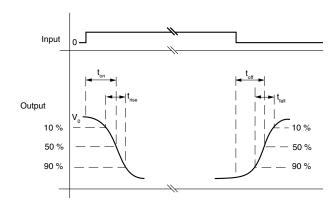
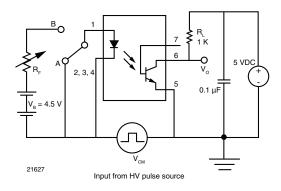


Fig. 1 - Switching Test Circuit

VO205AT, VO206AT, VO207AT, VO208AT

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COMMON MODE TRANSIENT IMMUNITY								
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT		
Common mode transient immunity at logic high	V_{CM} = 1000 V_{P-P} , R_L = 1 $k\Omega$, I_F = 0 mA	C _{MH}	-	5000	-	V/µs		
Common mode transient immunity at logic low	V_{CM} = 1000 V_{P-P} , R_L = 1 $k\Omega$, I_F = 10 mA	C _{ML}	-	5000	-	V/µs		



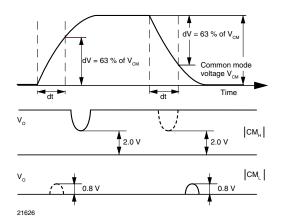


Fig. 2 - Test Circuit for Common Mode Transient Immunity

SAFETY AND INSULATION RATINGS								
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT		
Climatic classification (according to IEC 68 part 1)			-	40 / 100 / 21	=			
Polution degree			-	2	-			
Comparative tracking index		CTI	175	-	399			
Isolation test voltage	1 s	V _{ISO}	4000	-	-	V _{RMS}		
Peak transient overvoltage		V _{IOTM}	6000	-	-	V		
Peak insulation voltage		V _{IORM}	560	-	-	V		
Resistance (input to output)		R _{IO}	-	100	-	GΩ		
Safety rating - power output		P _{SO}	-	-	350	mW		
Safety rating - input current		I _{SI}	-	-	150	mA		
Safety rating - temperature		T _{SI}	-	-	165	°C		
External creepage distance			4	-	=	mm		
External clearance distance			4	-	=	mm		
Internal creepage distance			3.3	-	-	mm		
Insulation thickness			0.2	-	-	mm		

Note

As per IEC 60747-5-2, §7.4.3.8.1, this optocoupler is suitable for "safe electrical insulation" only within the safety ratings. Compliance with
the safety ratings shall be ensured by means of protective circuits.

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TYPICAL CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)

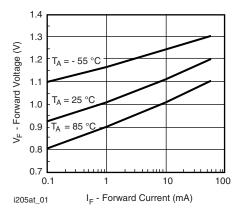


Fig. 3 - Forward Voltage vs. Forward Current

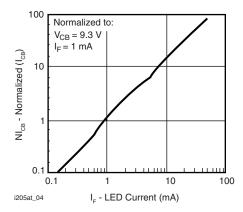


Fig. 6 - Normalized Collector-Base Photocurrent vs. LED Current

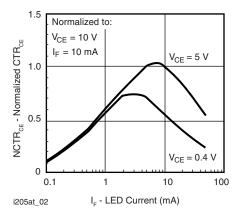


Fig. 4 - Normalized Non-Saturated and Saturated CTR_{CE} vs. LED Current

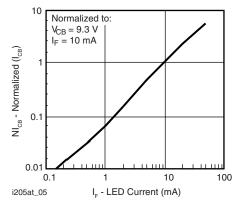


Fig. 7 - Normalized Collector-Base Photocurrent vs. LED Current

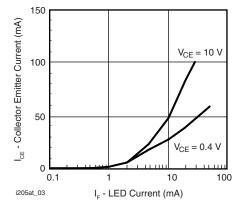


Fig. 5 - Collector Emitter Current vs. LED Current

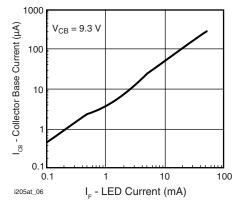
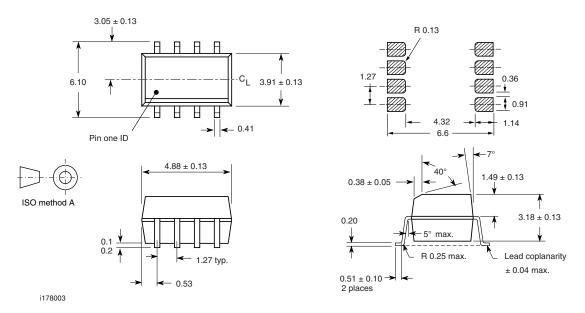


Fig. 8 - Collector Base Photocurrent vs. LED Current



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PACKAGE DIMENSIONS in millimeters



PACKAGE MARKING (example of VO207AT)



Note

• XXXX = LMC (lot marking code)

TAPE AND REEL PACKAGING

Dimensions in millimeters

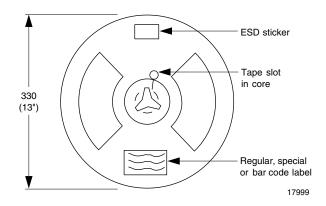


Fig. 9 - Tape and Reel Shipping Medium (EIA-481, revision A, and IEC 60286), 2000 units per reel

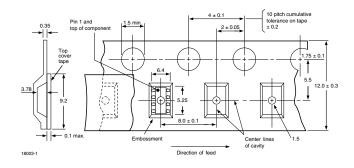


Fig. 10 - Tape Dimensions, 2000 Parts per Reel



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